



300V PNP SMALL SIGNAL TRANSISTOR IN SOT23

### Features

- BV<sub>CEO</sub> > 300V
- Ideal for Medium Power Amplification and Switching
- Complementary NPN Type: MMBTA42
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

#### **Mechanical Data**

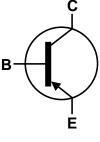
- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020

С

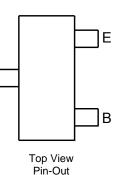
- Terminals: Finish-Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (€3)
- Weight: 0.008 grams (Approximate)



Top View



Device Symbol



#### Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
		- J	iteel size (inclies)		
MMBTA92-7-F	AEC-Q101	K3R	7	8	3,000
MMBTA92-13-F	AEC-Q101	K3R	13	8	10,000
MMBTA92Q-7-F	Automotive	K3R	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

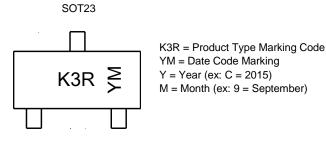
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

 Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**

Notes:



Date Code Key												
Year	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025	2026
Code	С	D	E	F	G	Н		J	K	L	М	Ν
Month	Jan	Feb	Mar	Apr	Mav	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



## **Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-300	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-300	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V
Collector Current	lc	-500	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	PD	300	mW
Thermal Resistance, Junction to Ambient	(Note 5)	R <sub>0JA</sub>	417	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

#### ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

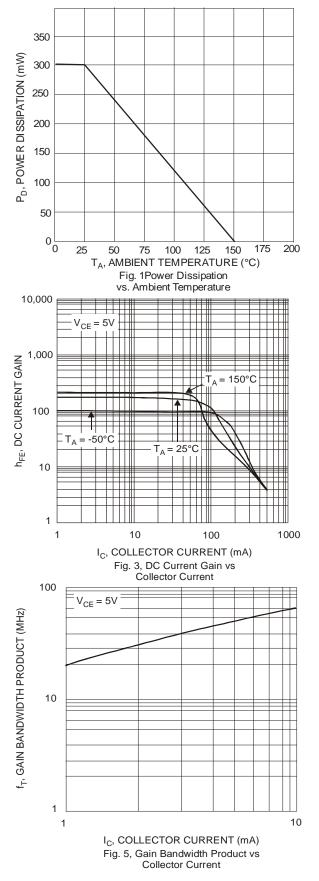
### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

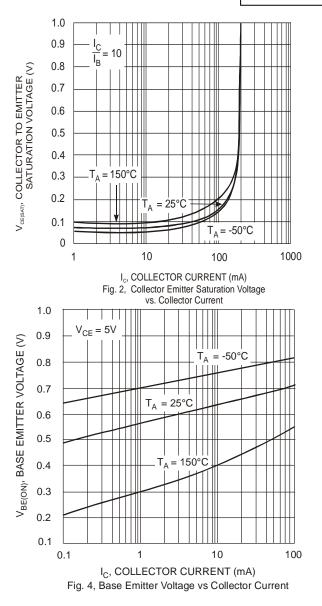
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					·
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-300		V	$I_{\rm C} = -100 \mu {\rm A}, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	-300	_	V	I <sub>C</sub> = -1.0mA, I <sub>B</sub> = 0
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5.0	_	V	$I_E = -100 \mu A$ , $I_C = 0$
Collector Cut-Off Current	I <sub>CBO</sub>	_	-250	nA	$V_{CB} = -200V, I_E = 0$
Emitter Cut-Off Current	I <sub>EBO</sub>		-100	nA	$V_{EB} = -3.0V, I_{C} = 0$
ON CHARACTERISTICS (Note 7)					·
		25			$I_{C} = -1.0 \text{mA}, V_{CE} = -10 \text{V}$
DC Current Gain	h <sub>FE</sub>	40	—	—	$I_{C} = -10 \text{mA}, V_{CE} = -10 \text{V}$
		25	—		$I_{C} = -30 \text{mA}, V_{CE} = -10 \text{V}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	-0.5	V	I <sub>C</sub> = -20mA, I <sub>B</sub> = -2.0mA
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	_	-0.9	V	I <sub>C</sub> = -20mA, I <sub>B</sub> = -2.0mA
SMALL SIGNAL CHARACTERISTICS	· · · ·		•		·
Output Capacitance	Cobo	_	6.0	pF	$V_{CB} = -20V, f = 1.0MHz, I_E = 0$
Current Gain-Bandwidth Product	f <sub>T</sub>	50	—	MHz	$V_{CE} = -20V, I_C = -10mA, f = 100MHz$

Note: 7. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



### **MMBTA92**

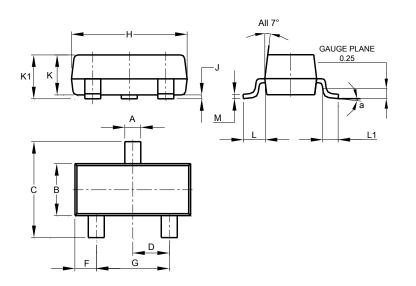






# **Package Outline Dimensions**

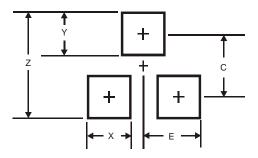
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version



	SOT23						
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
ĸ	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	8°						
All	Dimens	ions in	mm				

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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